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FAIRCHILD SEMICONDUCTOR™

February 1990
Revised August 2000

100314
Low Power Quint Differential Line Receiver

General Description

The 100314 is a monolithic quint differential line receiver with emitter-follower outputs. An internal reference supply (V_{BB}) is available for single-ended reception. When used in single-ended operation the apparent input threshold of the true inputs is 25 mV to 30 mV higher (positive) than the threshold of the complementary inputs. Unlike other F100K ECL devices, the inputs do not have input pull-down resistors.

Active current sources provide common-mode rejection of 1.0V in either the positive or negative direction. A defined output state exists if both inverting and non-inverting inputs are at the same potential between V_{EE} and V_{CC}. The defined state is logic HIGH on the $\overline{O}_a$–$\overline{O}_e$ outputs.

Features

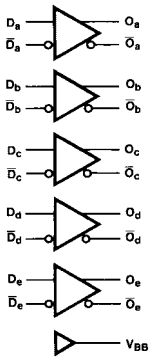
- 35% power reduction of the 100114
- 2000V ESD protection
- Pin/function compatible with 100114
- Voltage compensated operating range = –4.2V to –5.7V
- Available to industrial grade temperature range (PLCC package only)

Ordering Code:

Order Number	Package Number	Package Description
100314SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
100314PC	N24E	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.400 Wide
100314QC	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
100314QI	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square Industrial Temperature Range (–40°C to +85°C)

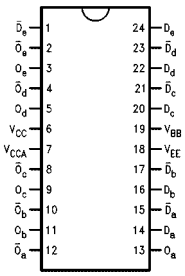
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

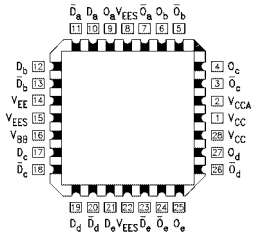


Connection Diagrams

24-Pin DIP/SOIC



28-Pin PLCC



Pin Descriptions

Pin Names	Description
D_a–D_e	Data Inputs
$\overline{D}_a$–$\overline{D}_e$	Inverting Data Inputs
O_a–O_e	Data Outputs
$\overline{O}_a$–$\overline{O}_e$	Complementary Data Outputs

Absolute Maximum Ratings (Note 1)

Storage Temperature (T_{STG})	−65°C to +150°C
Maximum Junction Temperature (T_J)	+150°C
Pin Potential to Ground Pin (V_{EE})	−7.0V to +0.5V
Input Voltage (DC)	V_{EE} to +0.5V
Output Current (DC Output HIGH)	−50 mA
ESD (Note 2)	≥2000V

Recommended Operating Conditions

Case Temperature (T_C)	
Commercial	0°C to +85°C
Industrial	−40°C to +85°C
Supply Voltage (V_{EE})	−5.7V to −4.2V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Commercial Version

DC Electrical Characteristics (Note 3)

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, T_C = 0°C to +85°C

Symbol	Parameter	Min	Typ	Max	Units	Conditions	
V_{OH}	Output HIGH Voltage	−1025	−955	−870	mV	V_{IN} = V_{IH} (Max)	Loading with
V_{OL}	Output LOW Voltage	−1830	−1705	−1620	mV	or V_{IL} (Min)	50Ω to −2.0V
V_{OHC}	Output HIGH Voltage	−1035			mV	V_{IN} = V_{IH}	Loading with
V_{OLC}	Output LOW Voltage			−1610	mV	or V_{IL} (Max)	50Ω to −2.0V
V_{BB}	Output Reference Voltage	−1380	−1320	−1260	mV	I_{VBB} = −250 µA	
V_{DIFF}	Input Voltage Differential	150			mV	Required for Full Output Swing	
V_{CM}	Common Mode Voltage	V_{CC} − 2.0		V_{CC} − 0.5	V		
V_{IH}	Single-Ended Input HIGH Voltage	−1110		−870	mV	Guaranteed HIGH Signal for All Inputs (with one input tied to V_{BB}) V_{BB} (Max) + V_{DIFF}	
V_{IL}	Single-Ended Input LOW Voltage	−1830		−1530	mV	Guaranteed LOW Signal for All Inputs (with one input tied to V_{BB}) V_{BB} (Min) − V_{DIFF}	
I_{IL}	Input LOW Current	0.50			µA	V_{IN} = V_{IL} (Min)	
I_{IH}	Input HIGH Current			240	µA	V_{IN} = $V_{IH\ (Max)}$, D_a–D_e = V_{BB}, $\overline{D}_a$–$\overline{D}_e$ = $V_{IL(Min)}$	
I_{CBO}	Input Leakage Current	−10			µA	V_{IN} = V_{EE}, D_a–D_e = V_{BB}, $\overline{D}_a$–$\overline{D}_e$ = $V_{IL\ (Min)}$	
I_{EE}	Power Supply Current	−60		−30	mA	D_a–D_e = V_{BB}, $\overline{D}_a$–$\overline{D}_e$ = $V_{IL\ (Min)}$	

Note 3: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

Commercial Version (Continued)
DIP AC Electrical Characteristics

V_{EE} = –4.2V to –5.7V, V_{CC} = V_{CCA} = GND

Symbol	Parameter	T_C = 0°C		T_C = +25°C		T_C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max		
f_{MAXFS}	Toggle Frequency (Full Swing)	250		250		250		MHz	(Note 2)
f_{MAXRS}	Toggle Frequency (Reduced Swing)	700		700		700		MHz	(Note 3)
t_{PLH} t_{PHL}	Propagation Delay Data to Output	0.65	1.90	0.65	2.00	0.70	2.00	ns	Figures 1, 2
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.35	1.20	0.35	1.20	0.35	1.20	ns	

SOIC and PLCC AC Electrical Characteristics

V_{EE} = –4.2V to –5.7V, V_{CC} = V_{CCA} = GND

Symbol	Parameter	T_C = 0°C		T_C = +25°C		T_C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max		
f_{MAXFS}	Toggle Frequency (Full Swing)	250		250		250		MHz	(Note 4)
f_{MAXRS}	Toggle Frequency (Reduced Swing)	700		700		700		MHz	(Note 5)
t_{PLH} t_{PHL}	Propagation Delay Data to Output	0.65	1.70	0.65	1.80	0.70	1.80	ns	Figures 1, 2
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.35	1.10	0.35	1.10	0.35	1.10	ns	
t_{PLH} t_{PHL}	Propagation Delay Data to Output	0.70	1.50	0.80	1.60	0.90	1.80	ns	PLCC only
t_{OSHL}	Maximum Skew Common Edge Output-to-Output Variation Data to Output Path		280		280		280	ps	PLCC only (Note 6)(Note 7)
t_{OSLH}	Maximum Skew Common Edge Output-to-Output Variation Data to Output Path		330		330		330	ps	PLCC only (Note 6)(Note 7)
t_{OST}	Maximum Skew Opposite Edge Output-to-Output Variation Data to Output Path		330		330		330	ps	PLCC only (Note 6)(Note 7)
t_{PS}	Maximum Skew Pin (Signal) Transition Variation Data to Output Path		320		320		320	ps	PLCC only (Note 6)(Note 7)

Note 4: Maximum toggle frequency at which V_{OH} and V_{OL} DC specifications are maintained.

Note 5: Maximum toggle frequency at which outputs maintain 150 mV swing.

Note 6: Output-to-Output Skew is defined as the absolute value of the difference between the actual propagation delay for any outputs within the same packaged device. The specifications apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}), or LOW-to-HIGH (t_{OSLH}), or in opposite directions both HL and LH (t_{OST}). Parameters t_{OST} and t_{PS} guaranteed by design.

Note 7: All skews calculated using input crossing point to output crossing point propagation delays.

Industrial Version

PLCC DC Electrical Characteristics (Note 8)

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, T_C = −40°C to +85°C

Symbol	Parameter	T_C = −40°C		T_C = 0°C to +85°C		Units	Conditions	
		Min	Max	Min	Max			
V_{OH}	Output HIGH Voltage	−1085	−870	−1025	−870	mV	V_{IN} = V_{IH} (Max)	Loading with
V_{OL}	Output LOW Voltage	−1830	−1575	−1830	−1620	mV	or V_{IL} (Min)	50Ω to −2.0V
V_{OHC}	Output HIGH Voltage	−1095		−1035		mV	V_{IN} = V_{IH}	Loading with
V_{OLC}	Output LOW Voltage		−1565		−1610	mV	or V_{IL} (Min)	50Ω to −2.0V
V_{BB}	Output Reference Voltage	−1395	−1255	−1380	−1260	mV	I_{VBB} = −250 µA	
V_{DIFF}	Input Voltage Differential	150		150		mV	Required for Full Output Swing	
V_{CM}	Common Mode Voltage	V_{CC} − 2.0	V_{CC} − 0.5	V_{CC} − 2.0	V_{CC} − 0.5	V		
V_{IH}	Single-Ended Input HIGH Voltage	−1115	−870	−1110	−870	mV	Guaranteed HIGH Signal for All Inputs (with one input tied to V_{BB}) V_{BB} (Max) + V_{DIFF}	
V_{IL}	Single-Ended Input LOW Voltage	−1830	−1535	−1830	−1530	mV	Guaranteed LOW Signal for All Inputs (with one input tied to V_{BB}) V_{BB} (Min) − V_{DIFF}	
I_{IL}	Input LOW Current	0.50		0.50		µA	V_{IN} = V_{IL} (Min)	
I_{IH}	Input HIGH Current		240		240	µA	V_{IN} = V_{IH} (Max), D_a–D_e = V_{BB}, $\overline{D}_a$–$\overline{D}_e$ = V_{IL} (Min)	
I_{CBO}	Input Leakage Current	−10		−10		µA	V_{IN} = V_{EE}, D_a–D_e = V_{BB} $\overline{D}_a$–$\overline{D}_e$ = V_{IL} (Min)	
I_{EE}	Power Supply Current	−60	−30	−60	−30	mA	D_a–D_e = V_{BB}, $\overline{D}_a$–$\overline{D}_e$ = V_{IL} (Min)	

Note 8: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

PLCC AC Electrical Characteristics

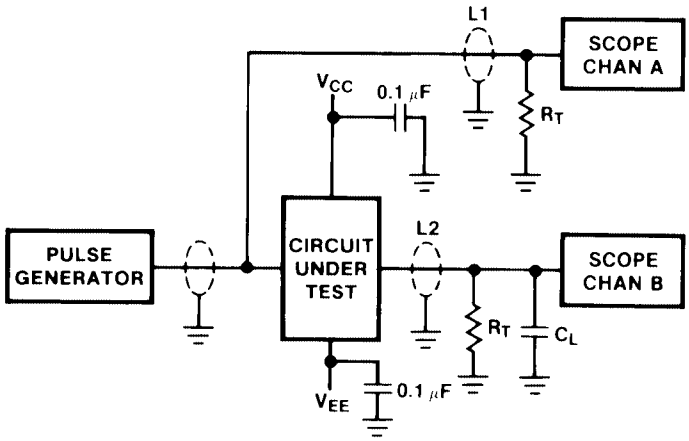
V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND

Symbol	Parameter	T_C = −40°C		T_C = +25°C		T_C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max		
f_{MAXFS}	Toggle Frequency (Full Swing)	250		250		250		MHz	(Note 9)
f_{MAXRS}	Toggle Frequency (Reduced Swing)	700		700		700		MHz	(Note 10)
t_{PLH} t_{PHL}	Propagation Delay Data to Output	0.65	1.70	0.65	1.80	0.70	1.80	ns	Figures 1, 2
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.20	1.40	0.35	1.10	0.35	1.10	ns	

Note 9: Maximum toggle frequency at which V_{OH} and V_{OL} DC specifications are maintained.

Note 10: Maximum toggle frequency at which outputs maintain 150 mV swing.

Test Circuit



Note:

- V_{CC}, V_{CCA} = +2V, V_{EE} = −2.5V
- L1 and L2 = equal length 50Ω impedance lines
- R_T = 50Ω terminator internal to scope
- Decoupling 0.1 μF from GND to V_{CC} and V_{EE}
- All unused outputs are loaded with 50Ω to GND
- C_L = Fixture and stray capacitance ≤ 3 pF

FIGURE 1. AC Test Circuit

Switching Waveforms

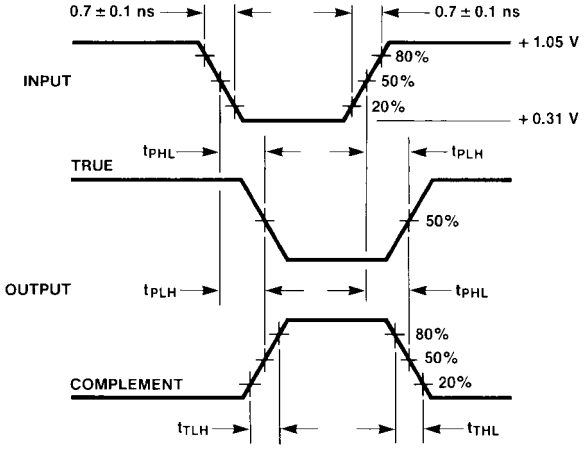
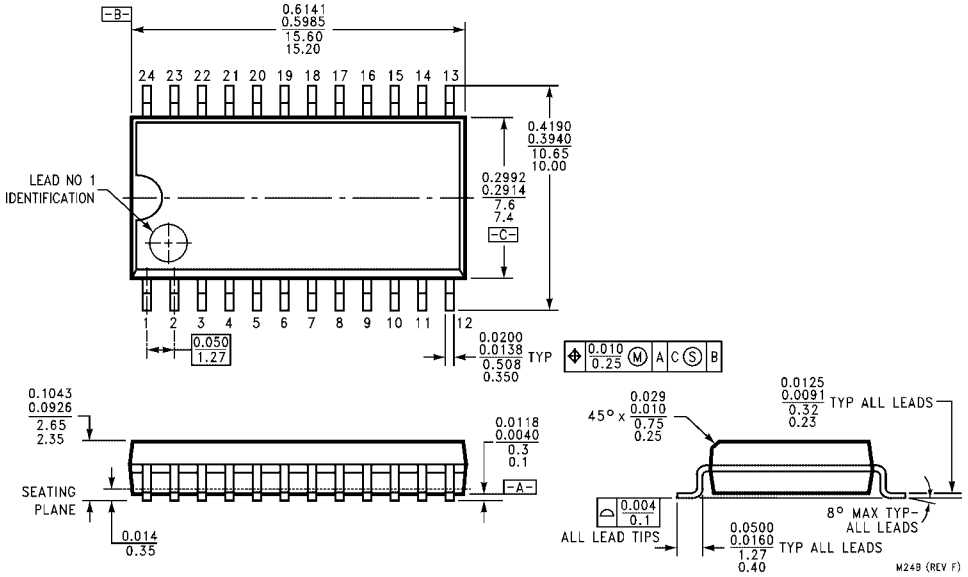
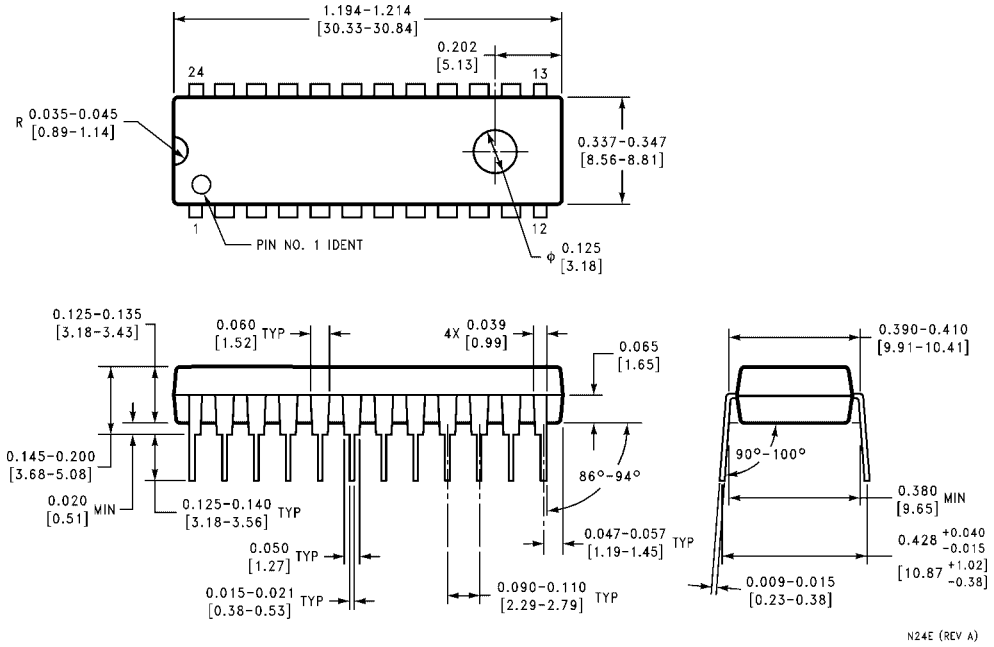


FIGURE 2. Propagation Delay and Transition Times

Physical Dimensions inches (millimeters) unless otherwise noted

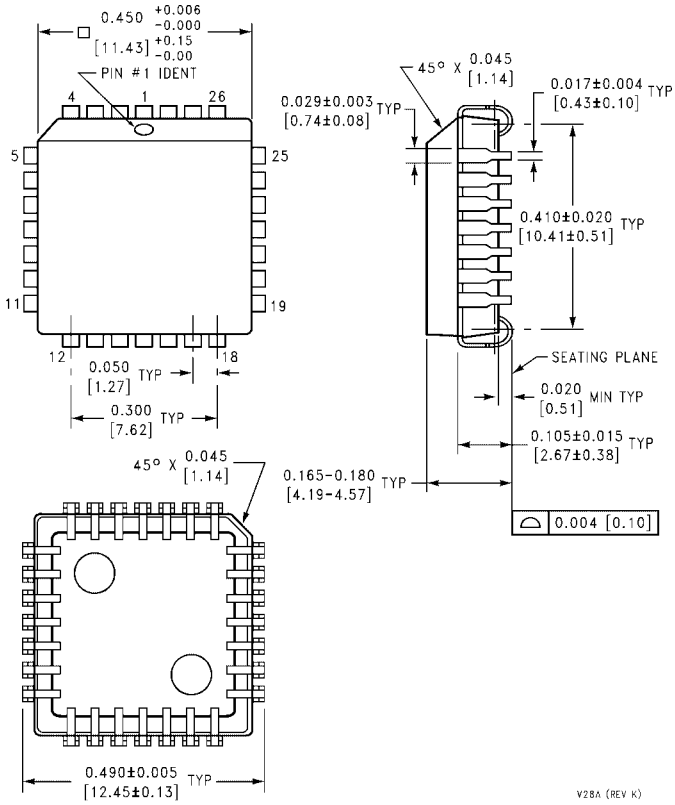


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.400 Wide
Package Number N24E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
Package Number V28A